# AMENDMENTS TO THE CLAIMS

The listing of claims will replace all prior versions, and listings, of claims in the application.

## Listing of Claims

 (Currently Amended) A method of making a diamond product having a projection or a depression on a surface thereof by etching, said method comprising the steps of:

forming a diamond substrate with a mask layer including a metal layer in at least one part thereof; and

etching said diamond substrate formed with said mask layer with a plasma of a mixed gas composed of a gas containing an oxygen atom and a gas containing a fluorine atom;

wherein said fluorine atom has a concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, said plasma is produced by generating a high-frequency discharge between two plate electrodes, said high-frequency discharge is generated by supplying an electric power of less than 1.0 W/cm² between said plate electrodes, and said mixed gas further contains nitrogen gas, thereby to form the diamond product having the projection or depression with a side face with an angle of inclination of at least 78 degrees,

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of pure oxygen the mixed gas with no nitrogen, where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.

## 2. (Cancelled)

### 10/774,417

 (Previously Presented) A method of making a diamond product according to claim 1, wherein said gas containing said fluorine atom is CF<sub>4</sub> gas; and

wherein said CF<sub>4</sub> gas has a concentration within the range of 0.02% to 3% with respect to the total number of molecules in said mixed gas.

 (Original) A method of making a diamond product according to claim 1, wherein said gas containing said oxygen atom is one of O<sub>2</sub>, CO<sub>2</sub>, and a mixed gas composed of O<sub>2</sub> and CO<sub>2</sub>.

Claims 5-11. (Cancelled)

12. (Currently Amended) A method of making a diamond product by etching a diamond substrate, said method comprising the steps of:

etching said diamond substrate using a plasma of a mixed gas, wherein the plasma of the mixed gas comprises oxygen atoms, fluorine atoms, and nitrogen atoms;

generating a high-frequency discharge between two plate electrodes by supplying an electric power of less than 1.0 W/cm² between said plate electrodes; and

wherein the mixed gas has a fluorine atom concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, and

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of the mixed gas with no nitrogen, where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.

### 13. (Cancelled)

- 14. (Previously Presented) The method of claim 12, wherein the diamond substrate has a mask, and wherein the diamond product has an angle of inclination of at least 78 degrees.
- 15. (Previously Presented) A diamond product having a projection or a depression on a surface thereof, the projection or depression having at least one side face with an angle of inclination of at least 78 degrees.
- 16. (Previously Presented) The method of claim 1, wherein the mixed gas contains an N<sub>2</sub> concentration that is not less than 2.5% and not more than 40%.
- 17. (Currently Amended) A method of making a diamond product having a projection or a depression on a surface thereof by etching, said method comprising the steps of:

forming a diamond substrate with a mask layer including a metal layer in at least one part thereof; and

etching said diamond substrate formed with said mask layer with a plasma of mixed gas composed of a gas containing an oxygen atom and a gas containing a fluorine atom;

wherein said fluorine atom has a concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, said plasma is produced by generating a high-frequency discharge between two plate electrodes, said high-frequency discharge is generated by supplying an electric power of at least 0.45 W/cm² between said plate electrodes, said mixed gas further contains nitrogen gas, and the mixed gas contains an N2 concentration

#### 10/774,417

that is not less than 2.5% and not more than 40%, thereby to form the diamond product having the projection or depression with a side face with an angle of inclination of at least 78 degrees, and

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of pure-exygen the mixed gas with no nitrogen, where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.

18. (Currently Amended) A method of making a diamond product having a projection or a depression on a surface thereof by etching, said method comprising the steps of:

forming a diamond substrate with a mask layer including a metal layer in at least one part thereof; and

etching said diamond substrate formed with said mask layer with a plasma of mixed gas composed of a gas containing an oxygen atom and a gas containing a fluorine atom;

wherein said fluorine atom has a concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, said plasma is produced by generating a high-frequency discharge between two plate electrodes, said high-frequency discharge is generated by supplying an electric power of at least 0.45 W/cm<sup>2</sup> between said plate electrodes, and said mixed gas further contains nitrogen gas, thereby to form the diamond product having the projection or depression with a side face with an angle of inclination of at least 78 degrees,

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B is not less than 2.5, where A is the intensity of an emission peak at a wavelength of 777 nm and B is the intensity of an emission peak at a wavelength of 558 nm, and

# 10/774,417

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of the mixed gas with no nitrogen, where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.